Qubit based on spin-singlet Yu-Shiba-Rusinov states

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The local magnetic moment of an interacting quantum dot occupied by a single electron can be screened by binding a Bogoliubov quasiparticle from a nearby superconductor. This gives rise to a long-lived discrete spin-singlet state inside the superconducting gap, known as the Yu-Shiba-Rusinov (YSR) state. We study the nature of the subgap states induced by a quantum dot embedded between two small superconducting islands. We show that this system has two spin-singlet subgap states with different spatial charge distributions. These states can be put in a linear superposition and coherently manipulated using electric-field pulses applied on the gate electrode. Such YSR qubit could be implemented using present-day technology.

\textbf{I. INTRODUCTION}

The coupling of an impurity carrying a local magnetic moment to a superconductor (SC) produces discrete subgap states, known as the Yu-Shiba-Rusinov states\textsuperscript{10}. These are spin-singlet bound states of Bogoliubov quasiparticles screening the impurity spin through antiferromagnetic Kondo exchange interactions. The energy gain from this coupling allows them to descend deep into the superconducting gap. Such subgap states appear in the spectra of many modern superconducting devices, where local magnetic moments arise in multiple ways, such as in adsorbed magnetic atoms or molecules, or in semiconductor quantum dots (QD)\textsuperscript{11–13}.

Systems of this kind are commonly modeled by extending the Anderson impurity model\textsuperscript{11} to the case of a superconducting bath, typically described by the BCS mean-field theory\textsuperscript{13}. Such Hamiltonians can be reliably solved by various numerical approaches, with the numerical renormalization group (NRG) proving the most successful\textsuperscript{14–16}.

Recent developments of experimental techniques enabled the fabrication of epitaxial SC islands in hybrid semiconductor-superconductor devices that are small enough for the Coulomb repulsion between the electrons to be important\textsuperscript{19–29}. This is taken into account by an effective charging term $E_C n_{SC}$, where $n_{SC}$ is the SC electron number operator and $E_C = e^2/2C$ is the charging energy with $C$ the island’s total capacitance\textsuperscript{21,29}. Incorporating this term into existing numerical techniques proves very difficult for two reasons. First, the electron number is not a conserved quantity in the BCS theory, which makes the implementation of an electron number operator problematic\textsuperscript{20}. Second, the Coulombic repulsion of the SC electrons makes the bath an interacting system, resulting in a problem which cannot be solved by any traditional impurity solver. Most theoretical treatments were based on ad hoc pictures relying on physical intuition rather than solving microscopic models.

In a recent paper\textsuperscript{31}, we presented a numerical method which does not suffer from the described problems. We introduced a model that builds on previous work in the context of ultrasmall superconducting grains\textsuperscript{21,22,24}, where the Richardson-Gaudin charge conserving model of superconductivity\textsuperscript{35–37} was successfully applied. This model describes the SC as a set of single particle energy levels with an attractive all-to-all pairing interaction and is well suited for the description of small SC systems. Using such model with a few hundred energy levels is very close to the BCS description appropriate in the thermodynamic limit, but retains the advantage of a well-defined number of particles and thus the ability to include in a clean and well-defined manner the Coulombic repulsion in the superconducting island into the model. Using the DMRG\textsuperscript{38–40} as the numerical solver, we are able to treat the charging term exactly and on the same level as other parameters and obtain accurate results in all parameter ranges. This approach was shown to give results in remarkable agreement with experiments in a setup of a QD with a single SC island\textsuperscript{41}. The implementation based on matrix product states (MPS) allows us to calculate basically any observable and allows for a detailed theoretical insight into the nature of the subgap states.

In this paper, we extend our analysis to a QD embedded between two SC islands. This is motivated by the considerable experimental interest in complex hybrid devices\textsuperscript{42–48}, and specifically in the two-channel problems where the impurity is coupled to two superconductors, e.g., embedded in a Josephson junction\textsuperscript{49,50}. In the absence of flux bias, to make the two superconductors behave as two independent channels at least one of them needs to have a significant charging energy. It may be noted that this is also the necessary condition for observing the two-channel Kondo effect in normal-state systems\textsuperscript{50,52}. Coupling an impurity spin to two independent SC islands produces two singlet subgap states, as a Bogoliubov quasiparticle from either of the channels can screen the impurity spin\textsuperscript{53}. In this work we investigate the nature of these subgap states in realistic models of hybrid devices, focusing on the singlet symmetry sector with an even total number of electrons in the system.

This paper is organized as follows. In Sec. II we introduce the model and discuss the technical issues arising from the presence of multiple superconducting regions. In Sec. III we discuss the symmetric situation with two equivalent superconductors, having the same SC gap $\Delta$ and the same charging energy $E_C$. In Sec. IV we analyze the asymmetric situation with different charging energies (e.g., one large superconductor and one small superconducting island). In Sec. VLA we model a realistic QD by reducing $U$, and thus moving away from the Kondo limit to an experimentally relevant regime. We briefly discuss the effect of decreased $U$ and then proceed in Sec. VI with the gate tuning effects that ultimately reveal a regime propitious to operating such devices as a YSR qubit. In
Section VII we calculate the electric transition moments, quantities important for manipulation of subgap states. We close with a discussion and a conclusion.

II. MODEL AND METHOD

A. Hamiltonian

The Hamiltonian consists of a single impurity level coupled to two SC island $^{115,155}$

$$H = H_{\text{imp}} + \sum_{\beta=L,R} \left( H^{(\beta)}_{\text{SC}} + H^{(\beta)}_{\text{hyb}} \right),$$

where

$$H_{\text{imp}} = \varepsilon n_{\text{imp}} + U n_{\text{imp},+} n_{\text{imp},-} = \frac{U}{2} (n_{\text{imp}} - \nu)^2 + \text{const.},$$

$$H^{(\beta)}_{\text{SC}} = \sum_{i,\sigma} \varepsilon_i c_{i,\sigma}^\dagger c_{i,\sigma} - \alpha d \sum_{i,j} \varepsilon_{ij} c_{i,\sigma}^\dagger c_{j,\sigma} c_{j,\sigma}^\dagger c_{i,\sigma} + E^{(\beta)}_{C} (n_{\text{SC}}^{(\beta)} - n_0^{(\beta)})^2,$$

$$H^{(\beta)}_{\text{hyb}} = \left( \frac{\nu_{\beta}}{\sqrt{N}} \right) \sum_{i,\sigma} \left( c_{i,\sigma}^\dagger d_{\sigma} + d_{\sigma}^\dagger c_{i,\sigma} \right).$$

Here $\varepsilon$ is the energy level and $U$ the electron-electron repulsion on the QD. The impurity term can be rewritten in terms of $\nu = 1/2 - \varepsilon/U$, the impurity level in units of electron number. $d_{\sigma}$ and $c_{i,\sigma,\beta}$ are the annihilation operators corresponding to the QD and the SC baths labeled by $\beta = L, R$ (left and right). The spin index is $\sigma = \uparrow, \downarrow$. Each SC bath is modelled by $N$ energy levels $\varepsilon_i$, spaced by a constant separation $d = 2D/N$, where $2D$ is the bandwidth. The levels are coupled all-to-all by a pairing interaction with strength $\alpha^{124,125}$. The SCs are coupled to the QD with the hybridisation strengths $\Gamma_{\beta} = \pi \rho \nu_{\beta}^2$, where $\rho = 1/2D$ is the normal-state density of states in each bath. The number operators are $n_{\text{imp}} = \sum_{\sigma} d_{\sigma}^\dagger d_{\sigma}$ for the impurity, and $n_{\text{SC}}^{(\beta)} = \sum_{i=1,\sigma} c_{i,\sigma,\beta}^\dagger c_{i,\sigma,\beta}$ for each SC bath. $E^{(\beta)}_C$ are the charging energies, with $n_0^{(\beta)}$ the optimal occupation of the SC island in units of electron charge. A sketch of the model system is shown in Fig. 1. In experimental setups, $\nu$, $n_0^{(\beta)}$ and $\Gamma_{\beta}$ are typically continuously tunable by the voltages applied to gate electrodes, while $U$, $E^{(\beta)}_C$ and $\Delta$ are device properties only weakly affected by the gate voltages.

![Figure 1](image1.png)

Figure 1. Schematic representation of the system: an interacting quantum dot embedded between two superconducting islands with charging energies $E^{(L)}_C$ and $E^{(R)}_C$. The Hamiltonian leads to terms that mix states in both superconductors (see Appendix A), but the effects of these terms become less physically significant with the increasing number of levels $N$, and disappear in the thermodynamic limit (with the gauge symmetry breaking).

B. Parameter choices

The calculations are performed for $N = 200$ energy levels in each SC. Using the half-bandwidth $D = 1$ as the energy unit, this corresponds to an inter-level spacing of $d = 2D/N = 0.01$. We choose $\alpha = 0.4$, which gives rise to the SC gap $\Delta = 0.165$ in each bath. This value is chosen so that an appropriate number of levels is engaged in the pairing interaction thus minimizing the finite-size effects, while also minimizing the finite-bandwidth effect. Disregarding the finite-size corrections, the low-energy properties of the model are universally scalable by $\Delta$.

We have implemented the Hamiltonian in the matrix product operator (MPO) form using matrices of dimension $9 \times 9$. The full expressions are given in Appendix B. We use the density matrix renormalization group (DMRG) to calculate the lowest eigenstates of the system in symmetry sectors defined by the total number of particles $n$ and the total $z$ component of spin $S_z$. We denote these by $|n, i\rangle$, with $i = 0$ the ground state (GS) in a given sector, and $i = 1$ the first excited state (ES). The states with even $n$ are spin-singlets with $S_z = 0$, the states with odd $n$ are spin-doublets with $S_z = \pm 1/2$. The reference state $|\psi_{\text{ref}}\rangle$ is defined by filling the system with an even-integer number of electrons $N$ in each SC and one electron in the QD, for a total of $n_{\text{ref}} = 2N + 1$ electrons. This
The nature and energies of the low-lying excitations are determined by the charge distribution controlled by \( \{n_{\alpha}(L), \nu, n_{\alpha}(R)\} \) and the impurity couplings \( \Gamma_L, \Gamma_R \). The parity of the occupation number in SC islands is important for superconducting pairing, resulting in the even-odd effect. Even occupation is favoured in each SC, while in the case of odd occupation a Bogoliubov quasiparticle is formed, increasing the energy by \( \Delta \). The charging energy \( E_C \) determines the energy cost of the situation where the filling of the superconducting island is different from \( n_0 \). If \( n_0 \) is an even integer, all excitations with odd SC island occupancy have a further energy cost of \( E_C \). In SC islands the charge gap therefore increases to \( \Delta + E_C \). The picture is reversed if \( n_0 \) is tuned to an odd integer value. The energy of the even-occupancy superconductor GS is then increased by \( E_C \), reducing the gap or even closing it completely at \( E_C = \Delta \). Further increase of \( E_C \) then reopens the gap which gradually develops the character of a Coulomb blockade gap. By introducing the impurity coupling \( \Gamma \), the unpaired Bogoliubov quasiparticles can antiferromagnetically bind to the impurity, giving rise to the YSR subgap states. The strength of the binding, and the resulting energy reduction, is characterised by \( \Gamma \). The subgap spectrum of the single-channel model with charging energy was thoroughly investigated in Ref. 31.

**C. Notation**

The eigenstates of the full model can be qualitatively characterized through the results of a simplified calculation with a small number of energy levels (at a very rough level even for \( N = 1 \)), which gives low-lying excitations that are in a one-to-one correspondence with those of the full problem and smoothly converge to the correct result with increasing \( N \). This motivates us to introduce a simplified notation for the basis states \( |S_L, S_{\text{imp}}, S_R\rangle \), where \( S_i \) denotes the spin in the left bath, at the impurity, and in the right bath, respectively. Thus the state consisting of an electron in the left bath bound into a spin-singlet state with the impurity electron is written as

\[
|\phi_L\rangle = (|\downarrow, \uparrow, 0\rangle - |\uparrow, \downarrow, 0\rangle)/\sqrt{2},
\]

while the spin-singlet in the right bath is

\[
|\phi_R\rangle = (|0, \uparrow, \downarrow\rangle - |0, \downarrow, \uparrow\rangle)/\sqrt{2}.
\]

It must be stressed, however, that the excitations in the large-\( N \) limit are not single-particle states, but rather collective many-body states involving many electron and hole states around the Fermi level.

**D. Fixed-phase vs. fixed-charge superconducting states**

In the BCS theory, the GS in the thermodynamic limit has a broken symmetry. In the grandcanonical picture for a fixed phase of the SC order parameter, the GS does not have a well-defined number of particles: it is a superposition of states with \( n, n + 2, n - 2, \ldots \) particles. Our model has, however, a finite size and we work in the microcanonical ensemble. The GS thus has a fixed number of particles, while the BCS phase is indeterminate. In calculations for a single SC bath this poses no conceptual nor technical difficulty, and the results are fully equivalent to those of the BCS theory in the limit of \( N \to \infty \).

The situation is different in the presence of two SC baths with finite sizes. When they have small charging energies (the \( E_C \to 0 \) limit), one of them can act as a particle reservoir for the other. Let us consider the situation with \( n_{\text{ref}} = 2N + 1 \) electrons in the system, for \( \Gamma_i \to 0 \). We find that the GS has...
\( \mathcal{N} \) particles in each SC bath, the remaining one occupying the QD level. The first ES has a configuration \((\mathcal{N} + 2, \mathcal{N} - 2)\), i.e., one Cooper pair moves from one SC to the other, at the energy cost of \(2d\) and tending to zero in the thermodynamic limit, as shown in Fig. 2(a). These (near)degenerate states are physical and not a numerical artifact. In the thermodynamic limit, the symmetry breaking would fix the phase difference between the SC baths and eliminate all states save one by singling out the suitable linear superposition of \((n_L, n_R)\) states. The lowest excitation in the equal-charge sector would then have energy \(2\Delta \) (i.e., the breaking of a single Cooper pair), as expected in the BCS picture. See Ref. [62], chapter 7, for an in-depth discussion of physics in small superconducting grains.

In a finite-size system the multitude of low-lying excitations for very small values of \(E_C\) poses a technical difficulty and, for example, hinders access to the more important Cooper-pair-breaking excitations on the scale of \(2\Delta\) in the spin-doublet sector. The same issue also arises in the spin-singlet sector, where each YSR singlet substate would have replicas at slightly higher energies differing only in the distribution of the Cooper pairs between the superconductors. Fortunately, here we are interested in small systems which intrinsically have non-zero charging energies \(E_C\). Moving a Cooper pair from one SC bath to another then costs \(4E_C^{(L)} + 4E_C^{(R)}\). When this energy cost is larger than \(2\Delta\), the \((\mathcal{N} + 2, \mathcal{N} - 2)\) states are pushed beyond the first excitation with the \((\mathcal{N}, \mathcal{N})\) configuration, which will then become the first ES of the system. We therefore constrain most of our calculation to the regime with \(E_C^{(L)} + E_C^{(R)} > \Delta/2\), where there are no technical issues and the lowest-lying ES with a broken Cooper pair appears in the doublet sector, see Fig. 2, where \(E_C^{(L)} = E_C^{(R)} = 0.8\Delta\). Fig. 2 shows the evolution of the subgap spectrum with increasing \(E_C\), illustrating the quick change in nature of the doublet ES when \(E_C > \Delta/4\). As \(\Gamma \approx 0\), the singlet \(n_{\text{ref}} + 1\) states are barely below the quasicontinuum and therefore have energy marginally lower than \(\Delta + E_C\).

We do not lose access to any important parts of the parameter space by the restriction to \(E_C^{(L)} + E_C^{(R)} > \Delta/2\), as precise calculations in the thermodynamic limit are possible using the NRG for \(E_C = 0\). Furthermore, for left-right mirror-symmetric problems, where the most relevant levels are the lowest ones in each parity subspace, the DMRG calculation could be implemented with the parity as a conserved quantum number after a suitable transformation of the Hamiltonian in the symmetry-adapted basis and an elaboration of its matrix-product-operator form. Alternatively, one could target excited states with appropriate parity by adding weight terms that penalize states with undesired parity in the optimization sweeps. The required parity operator could be implemented using tensor index reordering.

### III. SUBGAP STATES: CASE OF EQUIVALENT SUPERCONDUCTORS

In this section we consider the simplest case of symmetric devices composed of two equivalent SCs, i.e., \(E_C^{(L)} = E_C^{(R)} \equiv E_C\). We also set \(n_{\text{ref}}^{(L)} = n_{\text{ref}}^{(R)} = \mathcal{N}\) with even integer \(\mathcal{N}\), and restrict the discussion to the Kondo limit of \(U/\Delta = 30\) and \(\nu = 1\), where the occupation of the QD is pinned to 1.

#### A. Symmetric QD coupling

We first examine the case of symmetric coupling of the impurity to both baths, \(\Gamma_L = \Gamma_R \equiv \Gamma\). The system then has mirror symmetry and we denote the corresponding parity as gerade/ungerade in the following. The low-lying states with an odd number of electrons \(n_{\text{ref}}\) (spin-doublets) and an even number \(n_{\text{ref}} + 1\) (spin-singlets) are shown in the form of an energy-level diagram in Fig. 3. For \(\Gamma = 0\), the GS is a product state consisting of a BCS-like state of Cooper pairs in each channel and a decoupled electron sitting at the impurity site. The lowest ES with \(n_{\text{ref}} + 1\) electrons is the Bogoliubov state at the bottom of the quasi continuum (represented using orange shading) with energy \(\Delta + E_C\); the presence of the quasi-continuum of Bogoliubov states is confirmed by calculating a number of higher excited states.

For \(\Gamma > 0\), two states detach from the continuum to become the spin-singlet sub-gap states. This is clearly different from the situation in the \(E_C = 0\) limit, where only the gerade state is inside the gap, while the ungerade combination is fully decoupled from the impurity and remains inside the continuum (in the absence of flux bias). As \(\Gamma\) both states descend deeper into the gap, with the gerade state always having lower energy. This is different from the situation in the two-channel Kondo model where the singlet subgap states in a symmetric device are exactly degenerate. This is due to finite charge fluctuations in this model and in real QD devices and the different YSR wavefunctions, with an anti-node and a node at the impurity site for the gerade and ungerade combinations of Bogoliubov states, respectively. The continuum of excitations in the \(n_{\text{ref}} + 1\) sector begins at \(\Delta + E_C\). At \(\Gamma = 0\), it consists of product states of the BCS-like state with \(n_{\text{ref}}\) electrons and a Bogoliubov quasiparticle in one of the channels. The lowest lying continuum states are \(|\psi_{\text{ref}}\rangle \otimes (Q P_\beta \pm Q P_R)/\sqrt{2}\), where \(Q P_\beta\) denotes a Bogoliubov quasiparticle in channel \(\beta\). The small deviation from the \(\Gamma = 0\) gap value of \(\Delta + E_C\) is due to the \(\propto \Gamma^2\) virtual tunneling of quasiparticles between the channels; these processes are suppressed if \(E_C\) and/or \(U\) are increased.

The nature of the sub-gap singlets is investigated in Fig. 4. The first subgap state is an even (gerade) linear combination of spin-singlet YSR states from each channel

\[
|n_{\text{ref}} + 1, 0\rangle = |\psi_\beta\rangle \approx (|\phi_L\rangle + |\phi_R\rangle)/\sqrt{2}
\]

\[
= \frac{1}{2} \left[ (|\downarrow, \uparrow, \uparrow, 0\rangle - |\uparrow, \downarrow, \downarrow, 0\rangle) + (|0, \uparrow, \downarrow, \downarrow\rangle - |0, \downarrow, \uparrow, \downarrow\rangle)\right]
\]

where the final line shows that this state may also be interpreted as a spin-singlet formed between the impurity spin and an even-parity combination of Bogoliubov excitations from both electrodes, while the second is an odd (ungerade) com-
bination of the singlets,
\[
|n_{\text{ref}} + 1, 1\rangle = |\psi_u\rangle \approx (|\phi_L\rangle - |\phi_R\rangle)/\sqrt{2}
\]
\[
= \frac{1}{2} \left[ (|\downarrow, \uparrow\rangle - |\uparrow, \downarrow\rangle) - (|0, \uparrow\rangle - |0, \downarrow\rangle) \right]
\]
\[
= \frac{1}{2} \left[ (|\downarrow, \uparrow\rangle - |0, \uparrow\rangle) - (|\uparrow, \downarrow\rangle - |0, \downarrow\rangle) \right] ,
\]
with an alternative interpretation as a spin-singlet formed between the impurity spin and an odd-parity combination of Bogoliubov electrons from both electrodes. The parity of the states is confirmed by the calculation of the one-particle density matrices in the baths, \(\rho\) states is confirmed by the calculation of the one-particle density matrices in the baths, \(\rho\) states.

In Fig. 3(b), we illustrate the different composition of the two YSR singlets despite \(\Gamma_L = \Gamma_R\), thus further revealing the differences compared to the pure two-channel Kondo model. We plot excess charge compared to a reference doublet state (left) and the spin-spin correlations \(\langle S^i_{\text{imp}} : S^j_i \rangle\) between the impurity local moment and the SC single-particle energy levels \(i = 1, \ldots, N\), with energies between \(-1\) and \(1\) (right). Both plots indicate that the singlet is formed between the impurity and the excess electron, which is located close to the Fermi level, but the charge distribution is not identical in the two states. The width of the spin-spin correlation peak with increasing \(\Gamma\) is shown in Fig. 3(c) and is in qualitative agreement with the well known Kondo limits. At large coupling, the impurity is screened by the electron localized at \(r = 0\), with a broad distribution in energy, while at small coupling the screening is performed by the electrons with energies close to Fermi energy.

### B. Asymmetric QD coupling

We now examine the case of \(\Gamma_L \neq \Gamma_R\), see Fig. 5. We fix \(\Gamma_L + \Gamma_R = 0.1U\) and study the effect of the deviation from the equal-\(\Gamma\) tuning by simultaneously increasing \(\Gamma_R\) and decreasing \(\Gamma_L\). The energy diagram in panel (a) is accompanied by panels (b) and (c) illustrating the nature of the singlet states. In panel (b), the deviation from half-filling (even integer \(N = (n_{\text{ref}} - 1)/2\)) in each SC island is plotted. As we are in the limit of a very large \(U/\Delta\), the impurity occupation always remains very close to 1. Therefore, this plot uncovers the position of the unpaired quasiparticle in the SC channels. The impurity-channel spin-spin correlations, defined by \(\chi_{\beta} = \sum_{i=1}^{N} \langle S^i_{\text{imp}} : S^j_i(\beta) \rangle\) are presented in panel (c) and contain information on the screening of the impurity local moment.

With increasing \(\delta\Gamma\), the nature of the sub-gap states gradually changes from the inversion-symmetry eigenstates \(|\psi_g\rangle\) and \(|\psi_u\rangle\) with equal \(\chi\) in both channels to states that are closer to simple YSR singlets \(|\phi_L\rangle\) and \(|\phi_R\rangle\). The state with the lowest energy is the one corresponding to the larger hybridisation (\(\Gamma_R\) in our case, so \(|\phi_R\rangle\)), while the excited subgap state transforms into \(|\phi_L\rangle\). The energy of the excited subgap state increases as \(\Gamma_L\) is decreased, and it finally merges with the continuum when the left channel decouples from the system at \(\delta\Gamma \rightarrow 0.2\) (therefore \(\Gamma_L \rightarrow 0\)). This is different from the superconducting two-channel Kondo model, where breaking the coupling symmetry quickly pushes the second excited state beyond the gap\(^2\). We note also that in the normal-state two-channel Kondo problem a small difference in couplings immediately leads to a cross-over to a Fermi-liquid fixed point strictly at zero temperature, with one of the channels completely decoupled. In problems with a superconducting gap the renormalization is terminated at the scale of the gap, thus a complete decoupling of a second channel does not occur except in the cases of extreme asymmetry.

### IV. SUBGAP STATES: CASE OF NON-EQUIVALENT SUPERCONDUCTORS

The experimental interest in devices where the QD is embedded between one macroscopic SC contact and one SC island provides the motivation for considering the case of strongly differing charging energies. The asymmetry in the charging energies induces a preference for even occupation in the channel with larger \(E_C\). In the singlet sector with an even total number of particles, this implicitly favours the spin-
Figure 4. Singlet subgap states. (a) Channel density matrix $\rho_{ij} = \langle c_i^\dagger c_j \rangle$ for the two singlet subgap states. $\Gamma / U = 0.2$, $E_C = 0.4\Delta$. The diagonal blocks represent intra-channel density matrices, while the off-diagonal parts represent the inter-channel correlations. (b) Occupation and spin-spin correlations between the impurity and the baths. $\Delta n_i$ is the excess charge compared to the reference doublet state at $\Gamma \to 0$. $\Gamma / U = 0.2$, $E_C = 0.4\Delta$. (c) $\Gamma$ dependence of the width of the spin-spin correlation peak. $E_C = 0.4\Delta$.

Figure 5. Equivalent superconductors, asymmetric QD coupling. The dependence of the subgap states on $\delta \Gamma = \Gamma_R - \Gamma_L$ with the sum $\Gamma_L + \Gamma_R = 0.2U$ kept constant. (a) Subgap spectrum. Subgap states are accompanied by sketches indicating their nature. The orange shaded area represents the continuum of states in the $n_{ref} + 1$ sector. (b) Deviation from half-filling in the superconductors for the singlet subgap states. (c) Spin-spin correlations between the impurity and the baths for the singlet subgap states. The value of $-3/4$ corresponds to a pure (saturated) singlet configuration.

singlet YSR state formed between the impurity spin with a decoupled Bogoliubov quasiparticle in the channel with smaller $E_C$.

In this section, the results will be presented by plotting the evolution of the subgap states with changing $\Gamma_R$ at fixed $\Gamma_L$ for several different cases of non-equivalent superconductor parameters.

A. General considerations

Unequal charging energies influence the subgap states in one important aspect. The transition from the ungerade/gerade regime at small $\delta \Gamma$ towards $|\phi_L\rangle / |\phi_R\rangle$ subgap states at large $\delta \Gamma$ is decelerated (i.e., requires larger $\delta \Gamma$) if the strongly coupled channel has larger charging energy. The hybridisation favours configurations with the unpaired particle in the strongly coupled channel, while its charging energy enforces even occupation. The crossover occurs only when the larger $\Gamma$ is big enough to overcome the charging-energy penalty. This is demonstrated in Appendix C using a zero-bandwidth calculation.

B. Case of $E_C^{(L)} \gg E_C^{(R)}$

If the difference in $E_C$ is very large, this mechanism may cause the weakly coupled channel with large charging energy to almost completely decouple from the system. Such decoupling is illustrated in Fig. 6 for the case of $E_C^{(L)} \gg E_C^{(R)}$. The second subgap state does not descend deeper into the gap even for very large $\Gamma_R$, and we effectively obtain a single channel YSR singlet in the right channel, with a barely visible contribution from the left one.
Figure 6. Non-equivalent superconductors, \( E_C^{(L)} \ll E_C^{(R)} \). Subgap spectra dependence on \( \Gamma_R \) for constant \( \Gamma_L/U \) with \( E_C^{(L)} = 0.1 \Delta, E_C^{(R)} = 1.5 \Delta \). The value of \( \Gamma_L/U \) is indicated by the vertical dashed line.

C. Case of \( E_C^{(L)} \ll E_C^{(R)} \)

The sub-gap spectrum is most intriguing in the regime of \( E_C^{(L)} \ll E_C^{(R)} \). The charging terms favour even occupation in the right channel, therefore singlet screening in the left. For low \( \Gamma_R < \Gamma_L \) we observe the decoupled situation with a single subgap singlet \( |\phi_L\rangle \) and a decoupled right channel, Fig. 7. When \( \Gamma_R \) increases beyond \( \Gamma_L \), the system transitions into the regime where the hybridisation terms favor \( |\phi_R\rangle \), which is at the same time strongly disfavored by the charging energies. The lower subgap state transforms into a right-channel singlet state only for \( \Gamma_R \gg \Gamma_L \), when the strong hybridisation eventually overcomes the energy penalty due to \( E_C^{(R)} \). The excess charge and impurity-channel spin correlations shown in Fig. 7(b,c) illustrate the smooth transition of the lower singlet state between \( |\phi_L\rangle \) and \( |\phi_R\rangle \) limits. The spin correlations do not reach the saturated singlet value of \(-3/4\), indicating that even for very large \( \Gamma_R \) this state never quite obtains the nature of a pure singlet.

A second subgap state descends into the gap at some finite \( \Gamma_R \). Curiously, this \( i = 1 \) subgap state is not a left-channel YSR singlet as one might expect. Instead, the spin correlations show a very close relation to the \( i = 0 \) subgap state, increasingly so as \( \Gamma_R \) grows large. It transpires that the \( i = 1 \) is obtained from the \( i = 0 \) state by a transfer of a Cooper pair between the superconductors, i.e., while the \( i = 0 \) state has charge configuration \((N, 1, N + 1)\), the \( i = 1 \) state corresponds to \((N + 2, 1, N − 1)\). This allows the excited state to also obtain the energetically optimal nature of a right-channel YSR singlet. The transfer of two additional electrons only costs \( 4E_C^{(L)} \), corresponding to approximately \( 0.4 \Delta \) in the example shown (plus \( 2l \), a finite size effect).

The evolution of the channel occupation with increasing \( E_C \) asymmetry is shown in Fig. 8. By increasing \( \delta E_C \) (decreasing \( E_C^{(L)} \) and increasing \( E_C^{(R)} \)) the second subgap state approaches the \((N + 2, 1, N − 1)\) limit. For the parameters chosen here the charging energy penalty overcomes the \( \Gamma \) coupling just as \( E_C^{(L)} \rightarrow 0 \) and the occupation of the subgap states tends towards even occupation in the right channel, following the dominant charging energy effect. It should be stressed that the existence of such excited state is not a numerical artefact, but rather a signature of the physics of small SC islands with large charging energies.

D. YSR spin-singlet qubit

The regime of \( E_C^{(L)} < E_C^{(R)} \) with \( \Gamma_L < \Gamma_R \) seems to be the most appropriate for the investigation of the occurrence of two singlet subgap states, both well separated from the quasicontinuum at higher energies. In particular, it appears possible to achieve energy separation between the singlets that is lower than the transition energy from the upper level to the continuum. This is required for the implementation of qubits based on a linear superposition of the YSR singlet states, a
We consider a symmetric case with constant $\Gamma$ and $E_C$, comparable parameter values, which is typically a device property. If $E_C$ is small, there will be further singlet states with two, three, etc., Cooper pairs transferred between the superconductors, but the energy cost for those increase quadratically, resulting in non-monotonic spacing.

We further investigate this parameter regime in Sec. VI by considering the effects of tuning of the gate voltages in the system. These determine the favourable occupation of the system components, which can strongly influence the nature of the subgap states.

**V. REALISTIC QD**

While the Kondo limit of large electron-electron repulsion on the QD, $U \gg \Delta$, is useful for studying the nature of the Yu-Shiba-Rusinov sub-gap states in an ideal setting, a large class of real devices in current use operate in the regime of comparable parameter values, $U \approx \Delta \approx E_C$. By decreasing $U$ we move away from the Kondo limit where the QD behaves almost as a pure magnetic impurity, thus changing the nature of the subgap states from the YSR singlets (due to Kondo exchange interaction) by increasing the admixture of wavefunctions with Andreev-bound-state character (due to proximity effect) and the role of Coulomb interaction. The changing nature of the subgap singlets is demonstrated in Fig. 9.

We consider a symmetric case with constant $\Gamma/U = 0.1$ and $E_C = 0.7\Delta$. The level diagram in panel (a) shows that the energy difference between the sub-gap singlets is constant at large $U/\Delta$, determined mostly by $\Gamma/U$. With decreasing $U$, the upper singlet disappears into the continuum, while the lower one approaches the energy of the doublet ground state. In the absence of charging energy a pair of singlet ABS states is expected, with energy symmetrically above and below the doublet state, the difference between them determined by $\Gamma$. As $\Gamma/U$ is constant in our plot, $U \rightarrow 0$ means $\Gamma \rightarrow 0$ as well. This is why the lowest singlet and doublet states appear degenerate in the limit of small $U$. Furthermore, the charging energy breaks the degeneracy between the states with a different number of Cooper pairs in the SC islands, thus creating an energy difference between the $|0\rangle$ and $|2\rangle$ states on the QD. The ground singlet state is therefore predominantly of $P_2$ nature, while the excited state exhibits a larger $P_0$ contribution. Its energy cost is $4E_C$ (for an additional Cooper pair in the SC), so this state lives far beyond the continuum of decoupled excitations.

The QD charge fluctuations are presented in panel (b). They are small in the Kondo limit at $U \gg \Delta$, where the QD is a pure magnetic impurity and the only charge fluctuations correspond to virtual processes that generate the Kondo exchange scattering $J_K \propto \Gamma/U$. The charge fluctuation are also small for $U \ll \Delta + E_C$, because the charging effects in the SC islands strongly determine the QD occupation. They are hence the strongest in the cross-over regime, which is where the experimental devices operate. Finally, panel (c) shows the diagonal elements of the QD density matrix for the ground singlet state $|n_{\text{ref}} + 1, 0\rangle$. $P_n$ is the probability that the QD is in a state with occupation $n$. A crossover from a large magnetic moment in the Kondo regime (large $P_1$) towards Andreev bound states (large $P_0 + P_2$) is evident.

In order to obtain experimentally relevant results, from this point on we set $U$ to a value appropriate for contemporary InAs nanowire QD devices with top gate, $U/\Delta = 4$. The vertical dashed line at $U = 4\Delta$ demonstrates that this situation is far away from either limit, i.e., in the regime where charge fluctuations are important and the singlet states are neither YSR nor ABS. This competition between $U$, $\Delta$ and $E_C$ thus opens a new degree of complexity in the formation of the eigenstates. The subgap states are not simple combinations of singlets that we had previously examined, but rather some more complicated entities that generally exhibit non-integer occupation in each system component. The competition reduces the local moment on the QD, which diminishes the importance of hybridisation. We demonstrate the effect in Fig. 10, where the $\Gamma_R$ dependence of the sub-gap spectra is shown for $U = 4\Delta$. The decreased importance of $\Gamma$ becomes obvious when one compares this plot to Fig. 7(b), which is equal in all parameters, but at much larger $U$.

**VI. GATE VOLTAGE TUNING**

In the following section we investigate the gate voltage dependencies on the SC islands and in the QD. We mainly focus on the regime with two nearby subgap states presented in Sec. IV, but with $U = 4\Delta$. The goal in this section is twofold. Firstly, we presented results in the experimentally relevant regime. Second, we point out the optimal points for the operation of a proposed YSR qubit, and show that they occur when the energy difference between the sub-gap states is minimal.

**YSR qubit.** The relative position of the states is highly tunable: the energy difference from the gap edge is increased by increasing $\Gamma_R$. The energy difference between states depends on $E_C^{(L)}$, which is typically a device property. If $E_C^{(L)}$ is small, there will be further singlet states with two, three, etc., Cooper pairs transferred between the superconductors, but the energy cost for those increase quadratically, resulting in non-monotonic spacing.

We further investigate this parameter regime in Sec. VI by considering the effects of tuning of the gate voltages in the system. These determine the favourable occupation of the system components, which can strongly influence the nature of the subgap states.
wards an odd integer value \(N\) with varying dotted lines correspond to \(n\) vertical dashed line. \(E_G\) dependence on \(P\) states. (c) Probabilities \(P_n\) that in the lowest singlet state the QD is occupied by \(n\) electrons. Here we show the symmetric case with \(\Delta = 4\) \(\delta\). The gap width is \(\Delta + E_G\), the first being the charging energy scale of the QD and the latter of the SC islands. The vertical line at \(U/\Delta = 4\) corresponds to the regime in which realistic devices operate.

![Figure 9](image)

Figure 9. \(U\) dependence of the subgap states. (a) Subgap spectrum as a function of \(U\). (b) QD charge fluctuations in the subgap singlet states. (c) Probabilities \(P_n\) that in the lowest singlet state the QD is occupied by \(n\) electrons. Here we show the symmetric case with constant \(\Gamma = \Gamma_L = \Gamma_R = 0.1U\), \(E_G = E_G^{(L)} = E_G^{(R)} = 0.7\Delta\). \(U\) is scaled by \(\Delta + E_G\), the first being the charging energy scale of the QD and the latter of the SC islands. The vertical line at \(U/\Delta = 4\) corresponds to the regime in which realistic devices operate.

![Figure 10](image)

Figure 10. Realistic \(U = 4\Delta\) and \(E_G^{(L)} \ll E_G^{(R)}\). Subgap spectra dependence on \(\Gamma_R\) at constant \(\Gamma_L = 0.1U\), indicated by the black vertical dashed line. \(E_G^{(L)} = 0.1\Delta, E_G^{(R)} = 1.5\Delta\). The vertical dotted lines correspond to \(n_0^{(R)}\) sweeps presented in Fig. 11.

A. SC island gate voltage tuning

Fig. 11 illustrates the transformation of the subgap spectra with varying \(n_0^{(R)}\) (the gate voltage setting the occupancy of the right SC island) for a range of \(\Gamma_R\). By tuning \(n_0^{(R)}\) towards an odd integer value \(N + 1\), the large \(E_G^{(R)}\) enforces odd occupation in the right channel. This results in the decoupling of the left channel in a large interval around odd \(n_0^{(L)}\) and a single YSR-like subgap singlet. This is the same decoupling effect as seen in Fig. 6 where odd occupation of the right channel is enforced by a large \(E_G^{(L)}\) term at even \(n_0^{(L)}\).

As \(E_G^{(R)} > \Delta\) we observe the closure of the transport superconducting gap (the difference between the BCS-like doublet state \(|\psi_{ref}\rangle\) and the \(n_{ref} + 1\) quasi continuum) around odd \(n_0^{(R)}\), as predicted in the single-channel model. Increasing \(\Gamma_R\) summons a second bound state into the gap and increases the interval at which it is present. At very large \(\Gamma_R\) and close to \(n_0^{(R)} = N\) the excited subgap state exhibits a further decrease in energy, as exchange of the additional Cooper pair between the channels becomes favourable. The energy difference between the subgap states is minimal at a value of \(n_0^{(R)}\) which is somewhat lower than \(N\). This is due to the fact that we are considering the states in the \(n_{ref} + 1\) sector. These have an additional particle compared to half filling, thus having lower energy (compared to the reference \(|\psi_{ref}\rangle\) state) in the \((n_0^{(L)}, n_0^{(R)}) = (N, N - \delta)\) parameter point compared to the \((N, N + \delta)\) one, where \(\delta\) represents a small deviation from the half-filling point. If the states in the \(n_{ref} - 1\) sector were shown instead, the situation would be symmetrically mirrored over the \(n_0^{(R)} = N\) point, with the minimal energy difference at \(n_0^{(R)} = N + \delta\).

Fig. 12 shows the \(n_0^{(L)}\) dependence of the energy spectrum, corresponding to the case with large hybridization asymmetry shown in Fig. 11. The energy of the decoupled continuum states depends linearly on \(n_0^{(L)}\), with the slope given by \(E_G^{(L)}\). The gap width is \(\Delta + E_G^{(L)}\) when \(n_0^{(L)} = N\) and \(\Delta - E_G^{(L)}\) when \(n_0^{(L)} = N + 1\). While the energies of the states themselves exhibit a finite slope throughout the \(n_0^{(L)}\) range, the derivative of the energy difference becomes zero close to \(n_0^{(L)} = N + 1\). The system thus has an operational sweet spot in both island gate voltage tunings.

B. QD gate voltage tuning

In typical experimental setups, the QD gate voltage is easily tunable as well. In our model, this is represented by the term \(U/2(n_{imp} - \nu)^2\), where \(U/2\) plays the role of the QD charging energy and \(\nu\) is the favourable occupation of the QD set by the gate. Here we investigate the properties of the spectra for the system in the symmetrical and the strongly asymmetrical cases. Tuning the QD gate voltage away from the particle-hole (p-h) symmetric point \(\nu = 1\) decreases the local magnetic moment of the dot. A completely filled (or empty) QD thus does not have a local magnetic moment, suppressing the spin physics entirely. This means that the subgap states asymptotically approach the gap edge for extreme values of \(\nu\), resulting in the well-known eye-shaped dispersion for the YSR subgap states.
First we revisit the symmetrical system with $\Gamma_L = \Gamma_R$, $E_G^{(L)} = E_G^{(R)}$ and $n_0^{(L)} = n_0^{(R)} = N$. We show the energy diagram as a function of $\nu$ in Fig. [13]. In the p-h symmetric point at $\nu = 1$, the singlet subgap states are $|\psi_g\rangle$ and $|\psi_u\rangle$. Deviation from the p-h symmetric point does not break space-inversion symmetry, so the states retain their parity throughout. While increasing $\nu$ towards $\nu = 2$, the QD levels fills up, transforming the first subgap state into a $(N, 2, N)$ configuration. The roles of the singlet and doublet sectors switch, as now the singlet states can be formed without mustering the Bogoliubov quasiparticles, while the doublet states are forced to have odd occupation in the SC islands. The ground state in the doublet $n_{\text{ref}}$ sector has a full QD level, which is required by $\nu = 2$ and enforced by $U$. The resulting odd occupation in one of the SC islands results in the energy of this state at $\Delta + E_G$ above the lowest lying singlet state. In the singlet sector, the first excitation consists of a broken Cooper pair in one of the channels, which does not change the occupation of the channels and therefore costs $2\Delta$. Decreasing $\nu$ has the opposite effect of emptying the QD level. The subgap states in the singlet $n_{\text{ref}} + 1$ sector are superpositions of the strongly coupled singlet states and states with an empty quantum dot and an additional Cooper pair in the SC: $\alpha (|N + 2, 0, N\rangle) |N, 0, N + 2\rangle + b (|\phi_L\rangle |\phi_R\rangle)$, where the plus sign applies to the first (gerade) and the minus sign is for the second (ungerade) subgap state. With decreasing $\nu$ the amplitude $a$ continuously increases at the cost of $b$, as the YSR singlets become less energetically favourable. Despite this, both states remain in the gap throughout the $\nu$ range, keeping their gerade/ungerade nature. It should be noted that when $\nu = 0$, the true ground state is actually the singlet state in the $n_{\text{ref}} - 1$ sector, its energy being equal to that of the $n_{\text{ref}} + 1$ ground state at $\nu = 2$. The procedure of tuning the device to this point would therefore require two steps: First tuning the device into the ground state at $\nu = 2$ would fill it with $n_{\text{ref}} + 1$ electrons. Next, one should completely pinch off the device from the source and drain electrodes by strongly raising the tunnel barriers, and finally tune the QD gate voltage to $\nu = 0$. The pair of singlet subgap states could then be probed by microwave spectroscopy.

Next, consider the asymmetrical situation with $E_G^{(L)} \ll E_G^{(R)}$ and $\Gamma_L \ll \Gamma_R$. The energy diagram is shown in Fig. [13](b). The charging energy of the QD and the right channel are comparable and much larger than the charging energy of the left channel. The energy cost of the unfavourable occupation of the left channel is the relatively small factor of $E_G^{(L)}$. Thus the left channel tends to act as a reservoir for the rest of the system, primarily optimizing the charge configuration of the QD and the right channel. The subgap states have $(N, 1,N + 1)$ and $(N + 2, 1,N - 1)$ configurations at $\nu = 1$. By tuning the gate voltage away from the particle hole sym-
transitions in the SC-QD-SC devices is possible by inducing microwave
the system as a qubit, refer to the Discussion section.
states itself is minimal. For further comments on the use of
noise, while the energy difference between the two subgap
spot point, making the system relatively insensitive to electric
tuning is again a bit below half-filling, for the same reasons as when
couples to the electric dipole moment of the device
69,70
⟨}
no local moment on the QD. The first excitation is a broken
configuration for
ν
This is an optimal operation point for a YSR qubit, pointed
to by black arrows. The derivative of energy difference with
respect to all gate voltages has a root at this triple sweet-
metric point, the first subgap state assumes the
configuration for ν = 0 and (N, 2, N) for ν = 2. Such config-
urations do not allow for a second subgap state as there is
no local moment on the QD. The first excitation is a broken
Cooper pair in the SC - there is a continuum of such excita-
tions 2Δ above the ground state. The value of ν where the
energy difference between the two subgap states is minimal
is again a bit below half-filling, for the same reasons as when
tuning n0.

This is an optimal operation point for a YSR qubit, pointed
to by black arrows. The derivative of energy difference with
respect to all gate voltages has a root at this triple sweet-
spot point, making the system relatively insensitive to electric
noise, while the energy difference between the two subgap
states itself is minimal. For further comments on the use of
the system as a qubit, refer to the Discussion section.

VII. ELECTRIC TRANSITION MOMENTS

Manipulation of the subgap states in the same charge sector
in the SC-QD-SC devices is possible by inducing microwave
transition. The electric field of a linear resonator typically
couples to the electric dipole moment of the device, but
coupling to the quadrupole moment is also possible in a triple
quantum dot architecture. In order to demonstrate that ma-
nipulation of subgap states in the proposed device is possible,
we calculate both quantities for the transitions between
the two subgap single states.
The matrix element for the transition dipole moment is
⟨1|qr|0⟩, where r is the position operator. In the language
of our model with two point-like SC islands at unit distance
from the QD, this is (up to a constant prefactor) equivalent to:
⟨1|nL − n0⟩ − ⟨nR − n0⟩. The n0 factors represent the
charge accumulated on the gate electrodes, but their contribu-
tion is nullified by the orthogonality of the subgap states. This
gives the expression for the transition dipole moment D =
⟨1|nL − nR⟩. Following the same arguments, the quadrupole
moment ⟨1|q2|0⟩ is written as Q = ⟨1|nL + nR⟩. In Fig. 14
the transition dipole and quadrupole moments for singlet sub-
gap states are shown. Panel (a) corresponds to states shown
in Fig. 11(a), while panel (b) corresponds to Fig. 13(b). Both
transition moments roughly follow the energy difference be-
tween the two singlet states, exhibiting a peak when the sin-
glets are close in energy and the system is close to its sweet
spot. Both quickly decrease to zero when one of the states
merges with the continuum.

VIII. DISCUSSION

Practical quantum computing, especially one that would be
cryptographically relevant, requires systems with a large num-
ber of qubit. This need will drive increasing integration and
scaling down of all constituent parts. Miniaturization of de-
vices based on superconducting regions will ultimately lead
to the use of SC islands, which will then become a ubiqui-
tous element. It thus appears pertinent to explore the possi-
ble advantages that these will bring. In this work we have
studied one possible implementation that makes use of two
separate SC islands that bring about two separate spin-singlet
YSR subgap states which may be used to store one qubit of

![Figure 13. QD gate voltage tuning with a realistic value of U ≈ 4Δ.](image)

- (a) $E_C = 0.8\Delta$
- (b) $E_C = 0.1\Delta$, $E_C^{(L)} = 1.5\Delta$

![Figure 14. Electric transition dipole moment D and quadrupole mo-
ment Q.](image)

- (a) Hybridisation strength $\Gamma_L$ dependence for parameters as in

Fig. 11(a). (b) QD gate voltage dependence for parameters as in

Fig. 13(b). The horizontal dashed line corresponds to the position of

the sweet spot in Fig. 13(b).
information. We now comment on the relation of this class of qubits to other known architectures, and on its relative merits and downsides.

The YSR spin-singlet qubit may at first appear related to the Andreev qubit in a Josephson junction. The Andreev qubit makes use of the Andreev bound states (ABS) in the even parity subsector: the basis states consist of zero or double occupancy of the ABS. This concept does not directly apply to the YSR spin-singlet states: these cannot be “doubly occupied” since only a single quasiparticle from a given SC island can bind antiferromagnetically to the impurity to form a singlet state. An Andreev qubit can be approximately modelled using a non-interacting QD which correspond to the $U \rightarrow 0$ limit of our model. The higher-energy singlet subgap state of the Andreev qubit at $U \rightarrow 0$ is not connected to the higher-energy singlet YSR state at $U \gg \Delta$. Starting from the $U = 0$, $E_c = 0$ limit, increasing $U$ or $E_C$ will rapidly drive the higher-energy spin-singlet Andreev state into the continuum. Conversely, the higher-energy YSR singlet will disappear in the continuum when moving away from the $U \gg \Delta$, $E_c \neq 0$ regime by decreasing $U$ or $E_c$.

The YSR singlet qubit is actually more closely related to the charge qubit in double QD systems. The basis states for the charge qubit correspond to the position of the single electron in either of the two QDs. This is similar to YSR singlet qubit states which likewise have different distribution of the wavefunction in space. In this sense, the SI-QD-SI device is a variant of a charge qubit in a non-homogeneous triple QD system, however with the qubit state encoded in a pair of complex many-body states, rather than in a single-particle position basis. Depending on the operating point of the device (parameter choice), the spatial structure of the YSR singlets differs. For example, the regime $E_C^{(L)} < E_C^{(R)}$ and $\Gamma_L < \Gamma_R$, discussed in subsection IV.C, corresponds to a pair of singlet states which mainly differ in the position in space of a single Cooper pair. In this respect, at this operating point the YSR qubit is actually very similar to the Cooper-pair box charge qubit.

The YSR singlet qubits are relatively insensitive to magnetic field noise and do not require any magnetic flux tuning through superconducting loops and are in this aspect similar to spin singlet qubits. The robustness with respect to magnetic field weakly depends on the $g$-factors of the subsystems (QD vs. SC islands). The Zeeman shifts of spin-singlet states are nearly proportional to the differences in the $g$-factors. Nevertheless, even in the case of different $g$-factors there exist operating points (such as the one discussed above) which are largely insensitive to the field, because both states are Zeeman shifted in the same way, since they differ mostly in the position of a Cooper pair (two-particle singlet confined within a single SC island, insensitive to the magnetic field to first order).

Finally, we mention the YSR qubits recently proposed in Ref. Those are based on classical magnetic moments (e.g. on high-spin magnetic adsorbates with large magnetic anisotropy) which have spontaneously broken spin symmetry and are sensitive to external magnetic field. Another key difference is that our platform requires a single local moment (QD) and two superconductors (SC islands), while their proposal requires two local moments (adatoms) and a singlet superconductor (surface of a bulk SC). Beside making use of YSR subgap states, the two approaches are thus quite different.

**IX. CONCLUSION**

We have explored the properties of the subgap states in the system of an interacting quantum dot coupled to two small superconducting islands, focusing on the spin-singlet subspase. We have uncovered regimes where two sub-gap singlets are present deep in the gap with good separation from the continuum states. Their energies can be tuned to obtain an energy difference suitable for manipulation with microwaves pulses. The transitions are facilitated by large electric dipole (and quadrupole) transition moments. Such devices could be built using the present-day technology. Using a third superconducting island, the scheme could be generalized to qutrits.

This class of devices has also interesting properties in the doublet subspace: two Bogoliubov quasiparticles, one from each superconducting island, could overscreen the impurity moment to produce an overscreened Yu-Shiba-Rusinov state, a state clearly distinct from the “decoupled” spin-doublet state.

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Appendix A: Transformation to mirror-symmetry-adapted (gerade/ungerade) basis

1. Transformation of the BCS Hamiltonian

The mirror-symmetric problem of a quantum dot described by the single-impurity Anderson model that is coupled to two BCS superconductors with the same gap $\Delta$ and the same superconducting phase $\phi$ maps to a single-channel problem using a simple transformation to the mirror-symmetry basis (gerade and ungerade parity):

$$
g_{i,\sigma}^\dagger = \frac{1}{\sqrt{2}} \left( c_{i,\sigma,L}^\dagger + c_{i,\sigma,R}^\dagger \right),$$

$$
u_{i,\sigma}^\dagger = \frac{1}{\sqrt{2}} \left( c_{i,\sigma,L}^\dagger - c_{i,\sigma,R}^\dagger \right).$$

One finds

$$
\Delta c_{i,\uparrow}^\dagger c_{i,\downarrow}^\dagger + \Delta c_{i,\uparrow}^\dagger c_{i,\downarrow}^\dagger \text{H.c.} = \Delta g_{i,\uparrow}^\dagger g_{i,\downarrow}^\dagger + \Delta u_{i,\uparrow}^\dagger u_{i,\downarrow}^\dagger \text{H.c.}
$$

There are no terms mixing the g/u superconductor modes, thus the ungerade superconductor fully decouples from the problem, resulting in a single-channel problem, as is the case for normal-state contacts. At mathematical level this is trivial, but physically it is less so. The cancellation of the mixed gerade/ungerade terms is due to the mean-field decoupling of the effective electron-electron interaction terms and implies the assumption of complete coherence between the condensates in both SC contacts.

If there exists a flux bias $\phi$, one proceeds in two steps. First one performs a gauge transformation

$$
e^{i\phi/4}_{c_{i,\sigma,L}} = e^{i\phi/4} c_{i,\sigma,L}^\dagger,$$

$$e^{-i\phi/4}_{c_{i,\sigma,R}} = e^{-i\phi/4} c_{i,\sigma,R}^\dagger,$$

$$e^{i\phi/4}_{d_{\sigma}} = e^{i\phi/4} d_{\sigma}^\dagger.$$

One then performs a transformation to g/u basis in terms of $\tilde{c}$ operators:

$$
g_{i,\sigma}^\dagger = \frac{1}{\sqrt{2}} \left( \tilde{c}_{i,\sigma,L}^\dagger + \tilde{c}_{i,\sigma,R}^\dagger \right),$$

$$\nu_{i,\sigma}^\dagger = \frac{1}{\sqrt{2}} \left( \tilde{c}_{i,\sigma,L}^\dagger - \tilde{c}_{i,\sigma,R}^\dagger \right).$$

One finds

$$
\Delta e^{i\phi/2} c_{i,\uparrow}^\dagger c_{i,\downarrow}^\dagger + \Delta e^{-i\phi/2} c_{i,\uparrow}^\dagger c_{i,\downarrow}^\dagger + t \sum_{\sigma} c_{i,\sigma,L}^\dagger d_{\sigma} + t \sum_{\sigma} c_{i,\sigma,R}^\dagger d_{\sigma} + \text{H.c.}
$$

$$= \Delta g_{i,\uparrow}^\dagger g_{i,\downarrow}^\dagger + \Delta u_{i,\uparrow}^\dagger u_{i,\downarrow}^\dagger + \sqrt{2}t \cos(\phi/4) \sum_{\sigma} g_{i,\sigma,d_{\sigma}^\dagger} = \Delta g_{i,\uparrow}^\dagger g_{i,\downarrow}^\dagger + \Delta u_{i,\uparrow}^\dagger u_{i,\downarrow}^\dagger + \sqrt{2}t \cos(\phi/4) \sum_{\sigma} u_{i,\sigma}^\dagger d_{\sigma} + \text{H.c.}
$$

The QD is coupled to the $g$ modes with the hybridisation multiplied by a factor $2 \cos^2(\phi/4)$ and to the $u$ modes with a factor $2 \sin^2(\phi/4)$. In the presence of phase-bias, the $u$ modes thus do not decouple. This leads to the second singlet YSR state.

More generally, for an Anderson-model QD coupled to an arbitrary number of BCS superconductors with arbitrary hybridisation strengths and arbitrary gap parameters (amplitude and phase), the BCS superconductors can be integrated out resulting in a single hybridisation function in the Nambu space. In this sense the problem is always effectively a single-channel problem. Nevertheless, the non-trivial structure of the hybridisation matrix as a function of frequency reflects the complexity of the setup and can lead to, for example, the existence of multiple singlet Yu-Shiba-Rusinov states in the presence of flux biases.
2. Transformation of the Richardson model

Given that the Richardson model is equivalent to the BCS model in the limit of large $N$, a similar procedure is possible. Applying the even odd transformation (A1) to the number conserving pairing hamiltonian

$$
\sum_{i,j} c_{i,\uparrow,L}^\dagger c_{i,\downarrow,L}^\dagger c_{j,\downarrow,L}^\dagger c_{j,\uparrow,L} + \sum_{i,j} c_{i,\uparrow,R}^\dagger c_{i,\downarrow,R}^\dagger c_{j,\downarrow,R}^\dagger c_{j,\uparrow,R},
$$

one finds three types of terms. There are intra-channel pairing terms:

$$
u_{i,\uparrow}^\dagger u_{i,\downarrow}^\dagger u_{j,\downarrow} u_{j,\uparrow} + g_{j,\uparrow}^\dagger g_{j,\downarrow}^\dagger g_{i,\downarrow} g_{i,\uparrow},
$$

the terms that pair levels between channels:

$$
u_{i,\uparrow}^\dagger u_{i,\downarrow}^\dagger g_{j,\downarrow} g_{j,\uparrow} + g_{j,\uparrow}^\dagger g_{j,\downarrow}^\dagger u_{i,\downarrow} u_{i,\uparrow},
$$

and finally the terms that mix single particle states from both channels:

$$
u_{i,\uparrow}^\dagger g_{i,\downarrow}^\dagger u_{j,\downarrow} u_{j,\uparrow} + g_{j,\uparrow}^\dagger u_{j,\downarrow}^\dagger u_{i,\downarrow}^\dagger g_{i,\uparrow}.
$$

The terms which couple $u$ and $g$ modes have random phase and give zero contribution in the limit of $N \to \infty$. The two channels therefore decouple in the Richardson model too.

Appendix B: MPO representation

We provide the matrix product operator representation of the Hamiltonian studied in this work. It is implemented with the impurity in the middle of the system, with $N$ sites on each side of it. An alternative implementation is possible with the impurity as the left-most site. We obtain exactly the same results with both approaches and do not observe very significant differences in computational efficiency between implementations. Left-most site (1 denotes the first level in the left channel):

$$W_1 = \left(I \ [\epsilon_1 + E^{(L)}_0 (1 - 2n_{0}^{(L)})] \hat{n}_1 + (g + 2E^{(L)}_0) \hat{n}_1 \hat{n}_{1\downarrow} \hat{v}^\dagger_{1\uparrow} F_1 \hat{v}^\dagger_{1\downarrow} F_1 - \hat{v}^\dagger_{1\downarrow} F_1 \hat{v}^\dagger_{1\uparrow} F_1 \ gc_{1\downarrow} c_{1\uparrow} \ gc^\dagger_{1\uparrow} c^\dagger_{1\downarrow} \ 2E^{(L)}_0 \hat{n}_1 \right).
$$

Here $F_i = (-1)^n$ is the local fermionic-parity operator, which gives phase of $-1$ if there is an odd number of electrons on the site. Charge operators are

$$\hat{n}_{i\sigma} = c_{i\sigma}^\dagger c_{i\sigma}, \quad \hat{n}_i = \sum_\sigma \hat{n}_{i\sigma},
$$

Generic site in the left half of the system ($i$ denotes a level in the left channel):

$$W_i = \begin{pmatrix}
1 & [\epsilon_i + E^{(L)}_0 (1 - 2n_{0}^{(L)})] & \hat{n}_i + (g + 2E^{(L)}_0) \hat{n}_i \hat{n}_{i\downarrow} \hat{v}^\dagger_{i\uparrow} F_i \hat{v}^\dagger_{i\downarrow} F_i - \hat{v}^\dagger_{i\downarrow} F_i \hat{v}^\dagger_{i\uparrow} F_i \ gc_{i\downarrow} c_{i\uparrow} \ gc^\dagger_{i\uparrow} c^\dagger_{i\downarrow} \ 2E^{(L)}_0 \hat{n}_i \\
0 & I & 0 & 0 & 0 & 0 & 0 & 0 & 0 \\
0 & 0 & F_i & 0 & 0 & 0 & 0 & 0 & 0 \\
0 & 0 & 0 & F_i & 0 & 0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 & F_i & 0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 & 0 & F_i & 0 & 0 & 0 \\
0 & 0 & 0 & 0 & 0 & 0 & F_i & 0 & 0 \\
0 & e_{i\uparrow}^\dagger e_{i\downarrow} \ 0 & 0 & 0 & 0 & 0 & F_i & 0 & 0 \\
0 & e_{i\downarrow}^\dagger c_{i\uparrow} \ 0 & 0 & 0 & 0 & 0 & 0 & F_i & 0 \\
0 & \hat{n}_i \ 0 & 0 & 0 & 0 & 0 & 0 & 0 & F_i \\
\end{pmatrix}.
$$
Impurity site:

\[
W_{\text{imp}} = \begin{pmatrix}
1 \epsilon_{\text{imp}} \hat{n}_{\text{imp}} + U \hat{n}_{\text{imp}} \hat{n}_{\text{imp}} & -d_{\uparrow} \hat{F} & -d_{\downarrow} \hat{F} & d_{\uparrow} \hat{F} & d_{\downarrow} \hat{F} & 0 & 0 & 0 \\
0 & I & 0 & 0 & 0 & 0 & 0 & 0 \\
0 & d_{\uparrow} & 0 & 0 & 0 & 0 & 0 & 0 \\
0 & d_{\downarrow} & 0 & 0 & 0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 & 0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 & 0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 & 0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 & 0 & 0 & 0 & 0
\end{pmatrix}.
\]  \hspace{1cm} \text{(B4)}

Generic site in the right half of the system (\(i\) denotes a level in the right channel):

\[
W_i = \begin{pmatrix}
1 \left[ \epsilon_i + E_C^{(R)} (1 - 2n_0^{(R)}) \right] \hat{n}_i + \left(g + 2E_C^{(R)}\right) \hat{n}_i \hat{n}_i & 0 & 0 & 0 & g_{i\uparrow} c_{i\uparrow} & g_{i\downarrow} c_{i\downarrow} & 2E_C^{(R)} \hat{n}_i \\
0 & I & 0 & 0 & 0 & 0 & 0 \\
0 & v_{c_{i\uparrow}} & F_i & 0 & 0 & 0 & 0 \\
0 & v_{c_{i\downarrow}} & 0 & F_i & 0 & 0 & 0 \\
0 & v_{c_{N\uparrow}} & 0 & 0 & F_i & 0 & 0 \\
0 & v_{c_{N\downarrow}} & 0 & 0 & 0 & F_i & 0 \\
0 & c_{i\uparrow} c_{i\downarrow} & 0 & 0 & 0 & 0 & I \\
0 & c_{i\downarrow} c_{i\uparrow} & 0 & 0 & 0 & 0 & I \\
0 & \hat{n}_i & 0 & 0 & 0 & 0 & I
\end{pmatrix}.
\]  \hspace{1cm} \text{(B5)}

Right-most site (\(N\) denotes the last level in the right channel):

\[
W_N = \begin{pmatrix}
1 \left[ \epsilon_N + E_C^{(R)} (1 - 2n_0^{(R)}) \right] \hat{n}_N + \left(g + 2E_C^{(R)}\right) \hat{n}_N \hat{n}_N & I \\
v_{c_{N\uparrow}} & I \\
v_{c_{N\downarrow}} & v_{c_{N\uparrow}} \\
v_{c_{N\uparrow}} & v_{c_{N\downarrow}} \\
v_{c_{N\downarrow}} & c_{N\uparrow} c_{N\downarrow} \\
c_{N\downarrow} c_{N\uparrow} & \hat{n}_N
\end{pmatrix}.
\]  \hspace{1cm} \text{(B6)}

Appendix C: Zero-bandwidth calculation of changing nature of subgap states

The contribution of the left and right channel singlets can be directly calculated in the zero bandwidth limit (the SC islands are represented by a single level \(N = 1\)), where the singlet ground state with two particles is \(|n = 2, i = 0 \rangle \approx A |\phi_L\rangle + B |\phi_R\rangle\). Fig. \ref{fig:GammaDep} shows the \(\Gamma_R\) dependence of the probability amplitudes \(A\) and \(B\). Colored arrows point to the \(|A| = |B|\) points, where the state is an equal superposition of the left and right channel singlets. When \(E_C^{(L)} = E_C^{(R)} = 0\), the equal superposition point occurs exactly at \(\Gamma_L = \Gamma_R\), while it is pushed towards larger \(\Gamma_R\) with increasing \(E_C^{(R)}\).
Figure 15. Probabilities of the $|\phi_L\rangle$ and $|\phi_R\rangle$ states for the lowest lying singlet state in the zero-bandwidth approximation ($N = 1$). The colored arrows point to the $|A^2| = |B^2|$ points. $E_C^{(R)} = 0$, various $E_C^{(L)}$. $N = 1$, $U = 10$, $\Gamma_L = 1$. 

\[ |n = 2, i = 0\rangle = A\phi_L + B\phi_R \]